



Docket No.: SON-1285/DIV
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Takashi Noguchi, et al

Conf. # 5551

Application No.: 10/752,705

Group Art Unit: 2813

Filed: January 8, 2004

Examiner: Jack S.J. Chen

For: FIELD EFFECT TRANSISTOR AND
FABRICATION THEREOF,
SEMICONDUCTOR DEVICE AND
FABRICATION THEREOF...

PRELIMINARY AMENDMENT WITH ALLOWED CLAIMS FOR RCE WITH IDS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

This is a preliminary amendment with an RCE for the above application, again presenting the allowed claims noted in the Notice of Allowance of September 19, 2007 for consideration with an IDS in a Japanese action in a corresponding application.

Unamended previously allowed Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 15 of this paper.